## PRELIMINARY DATA SHEET



Solid State Relay OCMOS FET

# PS7241E-1A

# 4-PIN SOP 400 V BREAK DOWN VOLTAGE 1-ch Optical Coupled MOS FET

#### **DESCRIPTION**

The PS7241E-1A is an optically coupled element that combines a GaAs infrared LED on the input side with a normally-open MOS FET on the output side to realize an excellent cost performance.

The small, thin package and high sensitivity of this element makes it ideal for battery-driven mobile devices, and its small offset voltage at power-on and good linearity are also make it suitable for controlling micro analog signals.

#### **FEATURES**

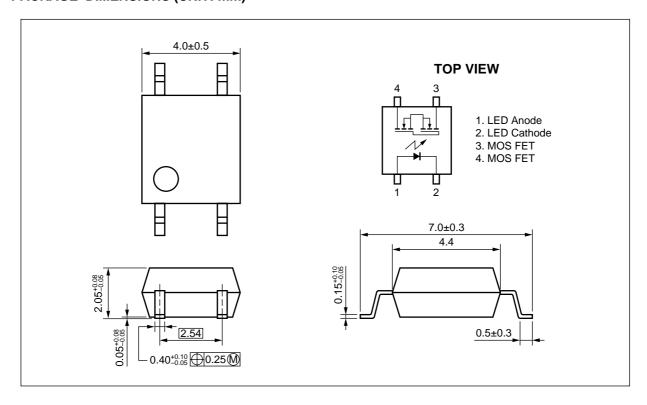
- Small and thin package (4-pin SOP, Height = 2.1 mm)
- 1 channel type (1 a output)
- Designed for AC/DC switching line changer
- · Low offset voltage
- Ordering number of taping product: PS7241E-1A-E3, E4, F3, F4
- · UL awaiting approval
- · BSI awaiting approval

#### **APPLICATIONS**

- Laptop PC, PDA
- Modem card
- · Telephone, FAX
- · Measurement equipment

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# PACKAGE DIMENSIONS (UNIT: mm)





#### **ORDERING INFORMATION**

Part Number	Package	Packing Style	Application Part Number*1
PS7241E-1A	4-pin SOP	Magazine case 100 pcs	PS7241E-1A
PS7241E-1A-E3		Embossed Tape 900 pcs/reel	
PS7241E-1A-E4			
PS7241E-1A-F3		Embossed Tape 3 500 pcs/reel	
PS7241E-1A-F4			

<sup>\*1</sup> For the application of the Safety Standard, following part number should be used.

# ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit	
Diode	Forward Current (DC)	lF	50	mA	
	Reverse Voltage	VR	5.0	V	
	Power Dissipation	Po	50	mW	
	Peak Forward Current <sup>*1</sup>	IFP	1	Α	
MOS FET	Break Down Voltage	VL	400	V	
	Continuous Load Current	lı	120	mA	
	Pulse Load Current <sup>2</sup> (AC/DC Connection)	ILP	240	mA	
	Power Dissipation	PD	300	mW	
Isolation Voltage *3		BV	1 500	Vr.m.s.	
Total Power Dissipation		Рт	350	mW	
Operating Ambient Temperature		TA	-40 to +85	°C	
Storage Temperature		Tstg	-40 to +100	°C	

<sup>\*1</sup> PW = 100  $\mu$ s, Duty Cycle = 1%

<sup>\*2</sup> PW = 100 ms, 1 shot

<sup>\*3</sup> AC voltage for 1 minute at  $T_A = 25^{\circ}C$ , RH = 60% between input and output



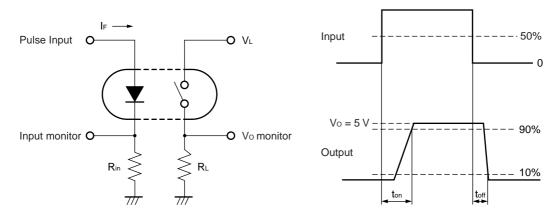
## RECOMMENDED OPERATING CONDITIONS (TA = 25°C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit	
LED Operating Current	lF	4	10	20	mA	
LED Off Voltage	VF	0		0.5	V	

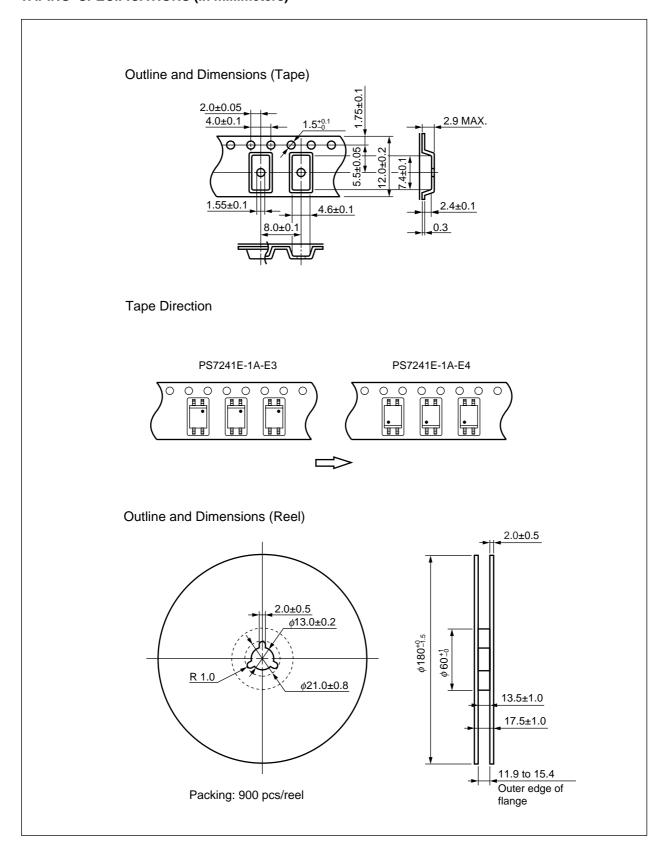
## **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.2	1.4	V
	Reverse Current	IR	V <sub>R</sub> = 5 V			5.0	μΑ
MOS FET	Off-state Leakage Current	Loff	V <sub>D</sub> = 400 V			1.0	μΑ
	Output Capacitance	Cout	V <sub>D</sub> = 0 V, f = 1 MHz		18		pF
Coupled	LED On-state Current	<b>I</b> Fon	IL = 120 mA			4.0	mA
	On-state Resistance	R <sub>on1</sub>	IF = 10 mA, IL = 10 mA		22	35	Ω
		Ron2	$I_F = 10 \text{ mA}, I_L = 120 \text{ mA}, t \le 10 \text{ ms}$		17	23	
	Turn-on Time <sup>*1</sup>	ton	If = 10 mA, Vo = 5 V, RL = 500 $\Omega$ ,		0.5	1.0	ms
	Turn-off Time <sup>*1</sup>	toff	PW ≥ 10 ms		0.07	0.2	
	Isolation Resistance	R <sub>I-O</sub>	Vi-o = 1.0 kVpc	10°			Ω
	Isolation Capacitance	Cı-o	V = 0 V, f = 1 MHz		0.5		pF

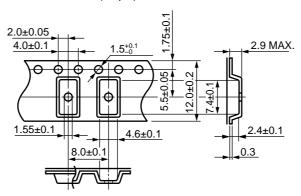
## \*1 Test Circuit for Switching Time



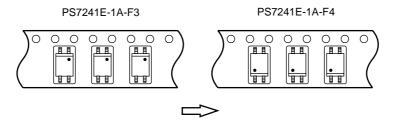
## **TAPING SPECIFICATIONS (in millimeters)**



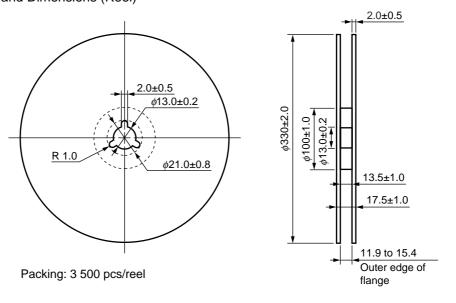
## Outline and Dimensions (Tape)



## **Tape Direction**



## Outline and Dimensions (Reel)





## RECOMMENDED SOLDERING CONDITIONS

## (1) Infrared reflow soldering

• Peak reflow temperature 260°C or below (package surface temperature)

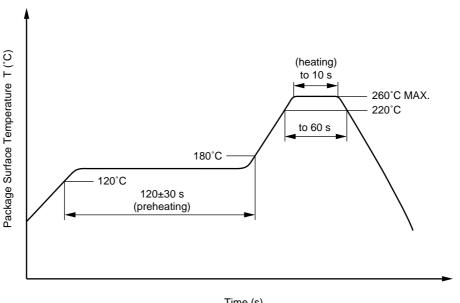
• Time of peak reflow temperature 10 seconds or less • Time of temperature higher than 220°C 60 seconds or less

• Time to preheat temperature from 120 to 180°C 120±30 s • Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

### Recommended Temperature Profile of Infrared Reflow



Time (s)

#### (2) Wave soldering

• Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

· Preheating conditions 120°C or below (package surface temperature)

· Number of times

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

#### (3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

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M8E 00.4-0110

NEC PS7241E-1A

#### Caution

**GaAs Products** 

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
  - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
  - 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

#### ▶ For further information, please contact

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